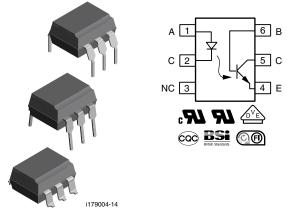
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# **Optocoupler, Phototransistor Output, with Base Connection**



#### DESCRIPTION

The CNY17 is an optically coupled pair consisting of a gallium arsenide infrared emitting diode optically coupled to a silicon NPN phototransitor.

Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output.

The CNY17 can be used to replace relays and transformers in many digital interface applications, as well as analog applications such as CRT modulation.

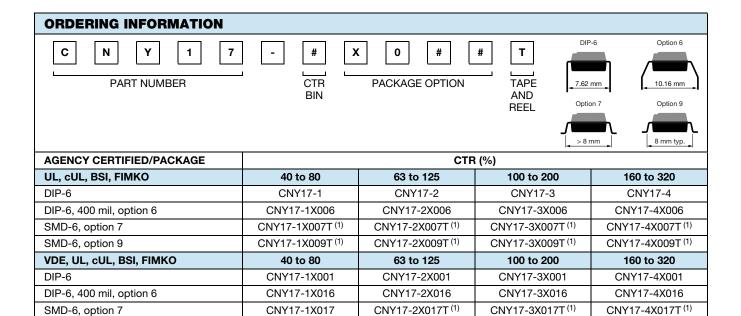
### FEATURES

- Isolation test voltage: 5000 V<sub>RMS</sub>
- · Long term stability
- Industry standard dual-in-line package
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912
   COMPLIANT

### AGENCY APPROVALS

Safety application model number covering all products in this datasheet is CNY17. This model number should be used when consulting safety agency documents.

- UL file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5)
- BSI IEC 60950, IEC 60065
- FIMKO EN60950
- CQC GB8898-2011



#### Note

<sup>(1)</sup> Also available in tubes, do not put T on the end.

SMD-6, option 9

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CNY17-2X019T<sup>(1)</sup>

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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)										
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT						
INPUT										
Reverse voltage		V <sub>R</sub>	6	V						
Forward current		I <sub>F</sub>	60	mA						
Forward surge current	t <sub>p</sub> ≤ 10 µs	I <sub>FSM</sub>	2.5	А						
LED power dissipation	at 25 °C	P <sub>diss</sub>	100	mW						
OUTPUT										
Collector emitter breakdown voltage		BV <sub>CEO</sub>	70	V						
Emitter base breakdown voltage		BV <sub>EBO</sub>	7	V						
Collector current		Ι <sub>C</sub>	50	mA						
	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	Ι <sub>C</sub>	100	mA						
Power dissipation		P <sub>diss</sub>	150	mW						
COUPLER										
Isolation test voltage between emitter and detector	t = 1 min	V <sub>ISO</sub>	5000	V <sub>RMS</sub>						
Storage temperature		T <sub>stg</sub>	-55 to +150	°C						
Operating temperature		T <sub>amb</sub>	-55 to +110	°C						
Soldering temperature <sup>(1)</sup>	2 mm from case, $\leq$ 10 s	T <sub>sld</sub>	260	°C						
Total power dissipation		P <sub>diss</sub>	250	mW						

#### Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(1)</sup> Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

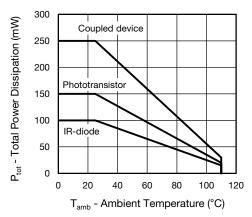


Fig. 1 - Total Power Dissipation vs. Ambient Temperature

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
Forward voltage	I <sub>F</sub> = 60 mA		V <sub>F</sub>		1.39	1.65	V	
Breakdown voltage	I <sub>R</sub> = 10 μΑ		V <sub>BR</sub>	6			V	
Reverse current	$V_R = 6 V$		I <sub>R</sub>		0.01	10	μA	
Capacitance	V <sub>R</sub> = 0 V, f = 1 MHz		Co		25		pF	
Thermal resistance			R <sub>th</sub>		750		K/W	

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**CNY17** 



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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb}$ = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
OUTPUT									
Collector emitter capacitance	$V_{CE} = 5 V$ , f = 1 MHz		C <sub>CE</sub>		5.2		pF		
Collector base capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz		C <sub>CB</sub>		6.5		pF		
Emitter base capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz		C <sub>EB</sub>		7.5		pF		
Thermal resistance			R <sub>th</sub>		500		K/W		
COUPLER									
Collector emitter, saturation voltage	$V_{F} = 10 \text{ mA}, I_{C} = 2.5 \text{ mA}$		V <sub>CEsat</sub>		0.25	0.4	V		
Coupling capacitance			CC		0.6		pF		
Collector emitter, leakage current	V <sub>CE</sub> = 10 V	CNY17-1	I <sub>CEO</sub>		2	50	nA		
		CNY17-2	I <sub>CEO</sub>		2	50	nA		
Conector emitter, leakage current		CNY17-3	I <sub>CEO</sub>		5	100	nA		
		CNY17-4	I <sub>CEO</sub>		5	100	nA		

Note

• Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

<b>CURRENT TRANSFER RATIO</b> ( $T_{amb} = 25 \text{ °C}$ , unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
	V <sub>CE</sub> = 5 V, I <sub>F</sub> = 10 mA	CNY17-1	CTR	40		80	%	
		CNY17-2	CTR	63		125	%	
		CNY17-3	CTR	100		200	%	
1.4		CNY17-4	CTR	160		320	%	
I <sub>C</sub> /I <sub>F</sub>	V <sub>CE</sub> = 5 V, I <sub>F</sub> = 1 mA	CNY17-1	CTR	13	30		%	
		CNY17-2	CTR	22	45		%	
		CNY17-3	CTR	34	70		%	
		CNY17-4	CTR	56	90		%	

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
LINEAR OPERATION	(without saturation)						
Turn-on time	$I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$		t <sub>on</sub>		3		μs
Rise time	$I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$		t <sub>r</sub>		2		μs
Turn-off time	$I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$		t <sub>off</sub>		2.3		μs
Fall time	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V}, \text{ R}_L = 75 \Omega$		t <sub>f</sub>		2		μs
Cut-off frequency	$I_F$ = 10 mA, $V_{CC}$ = 5 V, $R_L$ = 75 $\Omega$		f <sub>CO</sub>		110		kHz
SWITCHING OPERAT	TION (with saturation)						
	I <sub>F</sub> = 20 mA	CNY17-1	t <sub>on</sub>		3		μs
Turn on time	I <sub>F</sub> = 10 mA	CNY17-2	t <sub>on</sub>		4.2		μs
Turn-on time		CNY17-3	t <sub>on</sub>		4.2		μs
	I <sub>F</sub> = 5 mA	CNY17-4	t <sub>on</sub>		6		μs
	I <sub>F</sub> = 20 mA	CNY17-1	t <sub>r</sub>		2		μs
Rise time	I <sub>F</sub> = 10 mA	CNY17-2	t <sub>r</sub>		3		μs
Rise lime		CNY17-3	t <sub>r</sub>		3		μs
	I <sub>F</sub> = 5 mA	CNY17-4	t <sub>r</sub>		4.6		μs
	I <sub>F</sub> = 20 mA	CNY17-1	t <sub>off</sub>		18		μs
Turne off times	10	CNY17-2	t <sub>off</sub>		23		μs
Turn-off time	I <sub>F</sub> = 10 mA	CNY17-3	t <sub>off</sub>		23		μs
	I <sub>F</sub> = 5 mA	CNY17-4	t <sub>off</sub>		25		μs
Fall time	I <sub>F</sub> = 20 mA	CNY17-1	t <sub>f</sub>		11		μs
	I <sub>F</sub> = 10 mA	CNY17-2	t <sub>f</sub>		14		μs
		CNY17-3	t <sub>f</sub>		14		μs
	I <sub>F</sub> = 5 mA	CNY17-4	t <sub>f</sub>		15	1	μs

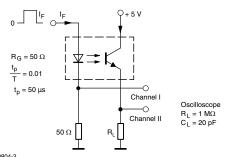
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Fig. 2 - Test Circuit, Non-Saturated Operation

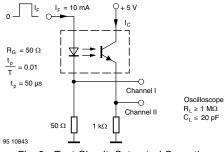


Fig. 3 - Test Circuit, Saturated Operation

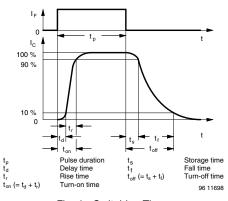


Fig. 4 - Switching Times

SAFETY AND INSULATION	N RATINGS			
PARAMETER		SYMBOL	VALUE	UNIT
MAXIMUM SAFETY RATINGS				
Output safety power		P <sub>SO</sub>	700	mW
Input safety current		I <sub>SI</sub>	400	mA
Safety temperature		T <sub>SI</sub>	175	°C
Comparative tracking index		CTI	175	
INSULATION RATED PARAMETER	S			
Maximum withstanding isolation volt	age	V <sub>ISO</sub>	5000	V <sub>RMS</sub>
Maximum transient isolation voltage	V <sub>IOTM</sub>	8000	V <sub>peak</sub>	
Maximum repetitive peak isolation voltage		V <sub>IORM</sub>	890	V <sub>peak</sub>
Insulation resistance	$T_{amb} = 25 \text{ °C}, V_{DC} = 500 \text{ V}$	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω
Isolation resistance	T <sub>amb</sub> = 100 °C, V <sub>DC</sub> = 500 V	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω
Climatic classification (according to	IEC 68 part 1)		55/115/21	
Environment (pollution degree in acc	ordance to DIN VDE 0109)		2	
Ourses and distance	Standard DIP-4		≥7	mm
Creepage distance	SMD		≥7	mm
Ole average distance	Standard DIP-4		≥8	mm
Clearance distance	SMD		≥8	mm
Insulation thickness	· · ·	DTI	≥0.4	mm

Note

• As per DIN EN 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

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### **TYPICAL CHARACTERISTICS** ( $T_{amb} = 25$ °C, unless otherwise specified)

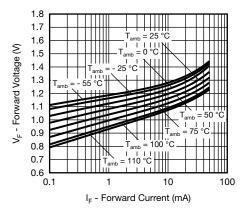


Fig. 5 - Forward Voltage vs. Forward Current

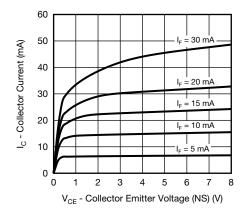


Fig. 6 - Collector Current vs. Collector Emitter Voltage (NS)

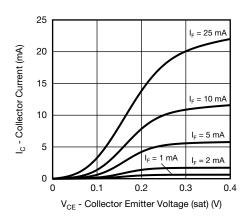


Fig. 7 - Collector Current vs. Collector Emitter Voltage (sat)

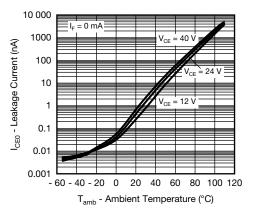


Fig. 8 - Leakage Current vs. Ambient Temperature

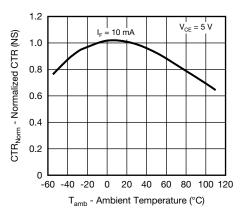


Fig. 9 - Normalized CTR (NS) vs. Ambient Temperature

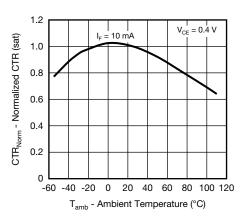


Fig. 10 - Normalized CTR (sat) vs. Ambient Temperature

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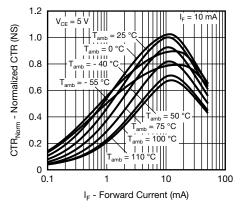


Fig. 11 - Normalized CTR (NS) vs. Forward Current

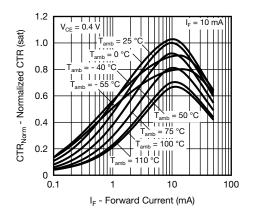


Fig. 12 - Normalized CTR (sat) vs. Forward Current

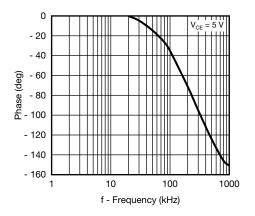


Fig. 13 - CTR Frequency vs. Phase Angle

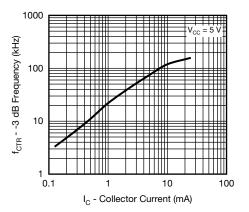


Fig. 14 - CTR -3 dB Frequency vs. Collector Current

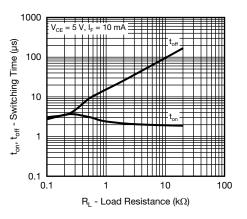


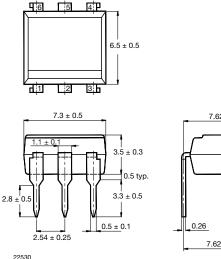
Fig. 15 - Switching Time vs. Load Resistance

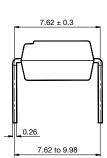
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#### **PACKAGE DIMENSIONS** in millimeters

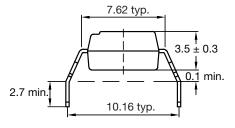


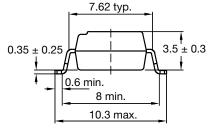


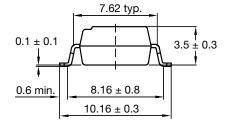
**Option 6** 

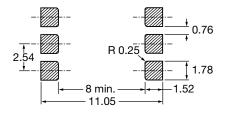
**Option 7** 

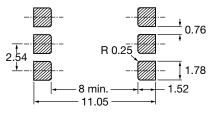
**Option 9** 











20802-34

#### PACKAGE MARKING



#### Notes

• VDE logo is only marked on option 1 parts. Option information is not marked on the part.

• Tape and reel suffix (T) is not part of the package marking.

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#### **TUBE AND TAPE INFORMATION**

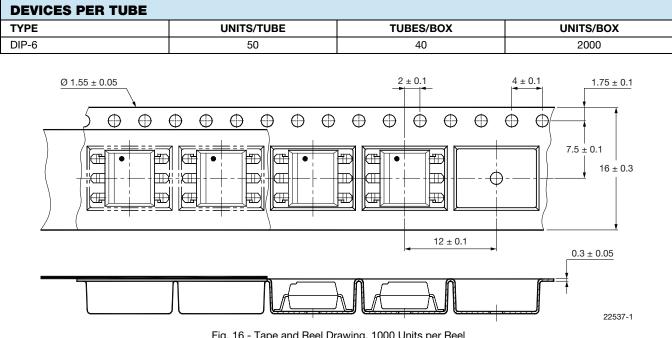


Fig. 16 - Tape and Reel Drawing, 1000 Units per Reel

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